

# **Slotted Optical Flag Switch**

## **Type OPB690**



## Features

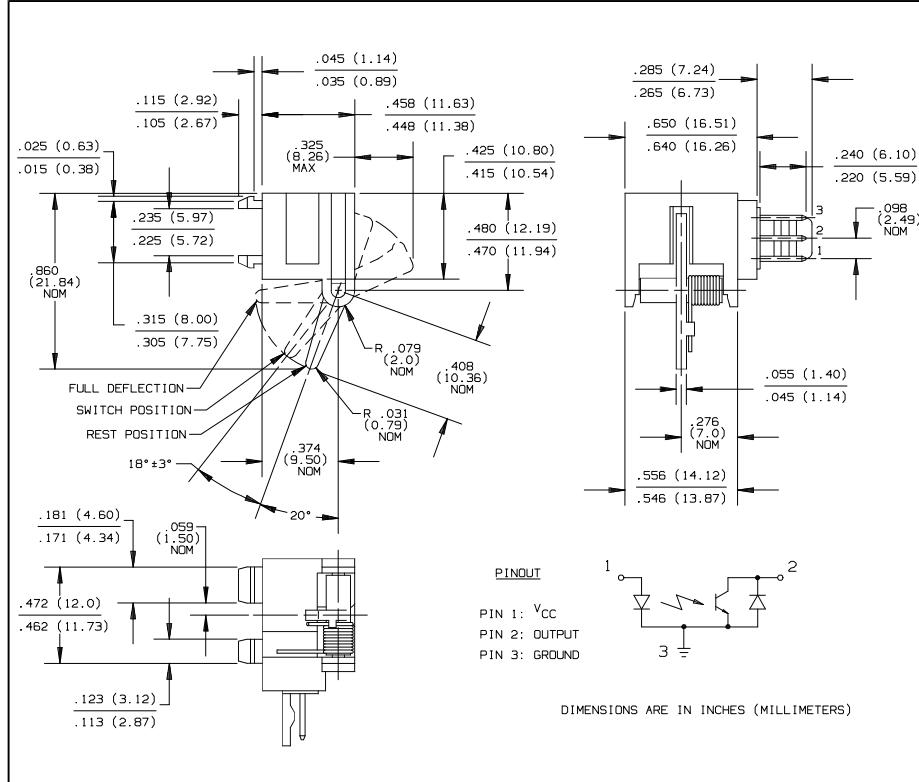
- Phototransistor output
  - Mechanical switch replacement
  - 3-pin connector (Ho Tien L2561-03), Molex compatible connector 5102 series housing and 5103 series terminal
  - Enhanced signal to noise ratio

## Description

The OPB690 consists of an NPN phototransistor and an infrared emitting diode in a molded plastic housing. The phototransistor has an enhanced low current roll-off which improves contrast ratio and immunity to background irradiance. A lever arm actuated flag interrupts the light beam, switching the transistor output between states that can readily drive logic gates.

This switch is designed to easily snap mount into a  $0.037" \pm 0.001"$  (0.94 mm) thick material with a rectangular opening of  $0.320" \pm 0.003" \times 0.472"$  (8.13 mm x 11.99 mm) minimum. Insertion into the punched side of metal is recommended.

Customized lever arms and spring torques can be designed for specific applications.



**Absolute Maximum Ratings ( $T_A = 25^\circ C$  unless otherwise noted)**

Storage and Operating Temperature . . . . . -40° C to +100° C

### **Input Diode**

Forward DC Current .....	50 mA
Peak Forward Current (1 µs pulse width, 300 pps) .....	3.0 A
Reverse DC Voltage .....	3.0 V
Power Dissipation .....	100 mW(1)

#### **Output Phototransistor**

<b>Output Phototransistor</b>	
Collector-Emitter Voltage . . . . .	30 V
Emitter Reverse Current . . . . .	10 mA
Collector DC Current . . . . .	30 mA
Power Dissipation . . . . .	200 mW(2)

Power  
Notes

- Notes:**

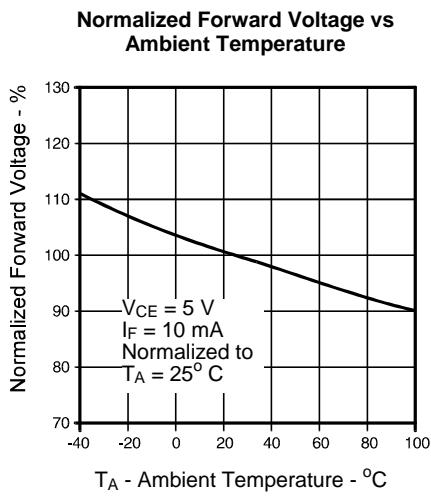
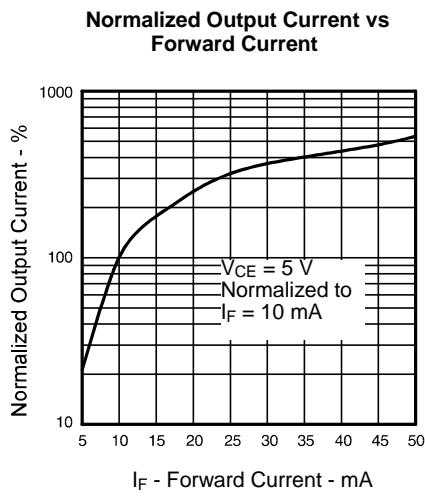
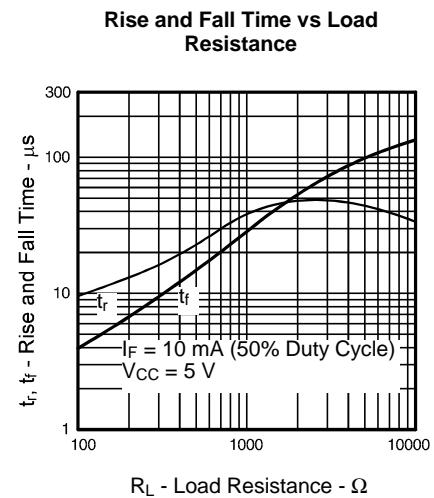
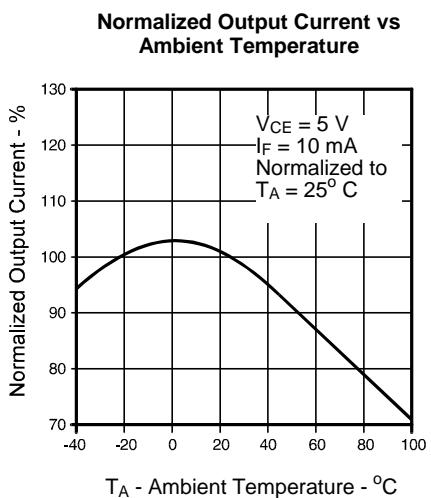
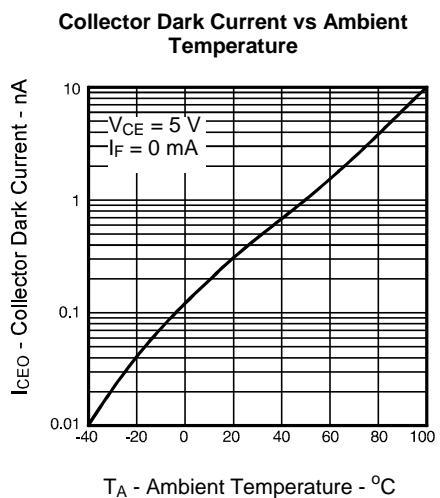
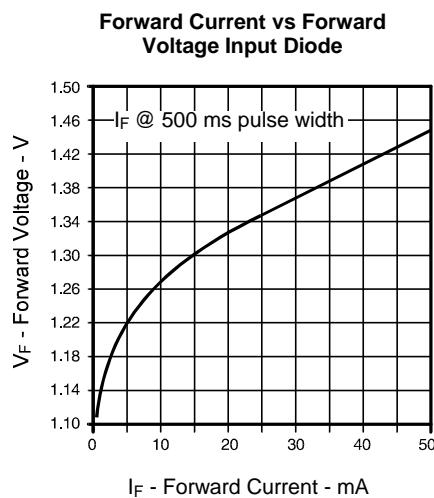
  - (1) Derate linearly 1.33 mW/ $^{\circ}$  C above 25 $^{\circ}$  C.
  - (2) Derate linearly 2.0 mW/ $^{\circ}$  C above 25 $^{\circ}$  C.
  - (3) "Off" condition exists when the lever arm is in the rest position (20 $^{\circ}$  from vertical) as shown in the figure.
  - (4) "On" condition exists when the lever arm is deflected clockwise 18 $^{\circ}$  +/- 3 $^{\circ}$  from the rest position (20 $^{\circ}$  from vertical) as shown in the figure.
  - (5) From the rest position to the switch point, lever torque measured at the end of the arm is 1.5 grams max.

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Electrical Characteristics ( $T_A = 25^\circ C$  unless otherwise noted)

SYMBOL	PARAMETER	MIN	MAX	UNITS	TEST CONDITIONS
<b>Input Diode</b>					
$V_F$	Forward Voltage		1.6	V	$I_F = 10 \text{ mA}$
$I_R$	Reverse Current		100	$\mu\text{A}$	$V_R = 3.0 \text{ V}$
<b>Output Phototransistor</b>					
$V_{(BR)\text{CEO}}$	Collector-Emitter Breakdown Voltage	30		V	$I_C = 100 \mu\text{A}$
$I_{ECO}$	Emitter Reverse Current		100	$\mu\text{A}$	$V_{EC} = 0.4 \text{ V}$
$I_{CEO}$	Collector-Emitter Dark Current		100	nA	$V_{CE} = 5 \text{ V}$
<b>Coupled</b>					
$V_{SAT}$	Saturation Voltage		0.4	V	$I_F = 10 \text{ mA}, I_C = 100 \mu\text{A}$ , Gap unblocked
$I_{C(\text{ON})}$	On-State Collector Current	600		$\mu\text{A}$	$I_F = 10 \text{ mA}, V_{CE} = 5 \text{ V}$

SLOTTED  
OPTICAL  
AMITICLES



Optek reserves the right to make changes at any time in order to improve design and to supply the best product possible.

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